PC364NJ0000F Series

Mini-Flat Package High CMR, AC Input, Low Input **Current Type Photocoupler**



Description

PC364NJ0000F Series contains an IRED optically coupled to a phototransistor.

AC input and Low input current type.

It is packaged in a 4-pin mini-flat.

Input-output isolation voltage(rms) is 3.75kV.

Collector-emitter voltage is 80V and CTR is 50% to 400% at input current of ±0.5mA.

Features

- 1. 4-pin Mini-flat package
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. AC input type
- 4. Low input current type ($I_{F}=\pm 0.5 \text{mA}$)
- 5. High collector-emitter voltage (V_{CEO} : 80V)
- 6. High noise immunity due to high common mode rejection voltage (CMR : MIN. 10kV/µs)
- 7. High isolation voltage between input and output $(V_{iso(rms)}: 3.75kV)$
- 8. RoHS directive compliant

Agency approvals/Compliance

- 1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC364)
- 2. Package resin : UL flammability grade (94V-0)

Applications

- 1. Programmable controllers
- 2. Facsimiles
- 3. Telephones

Notice The content of data sheet is subject to change without prior notice

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■ Internal Connection Diagram



1 Anode/Cathode

(Unit : mm)

- ② Cathode/Anode
- ③ Emitter
- ④ Collector

■ Outline Dimensions



Plating material : SnCu (Cu : TYP. 2%)



Date code (2 digit)

	1st o	digit		2nd digit		
		roduction		Month of production		
A.D.	Mark	A.D	Mark	Month	Mark	
1990	А	2002	Р	January	1	
1991	В	2003	R	February	2	
1992	С	2004	S	March	3	
1993	D	2005	Т	April	4	
1994	Е	2006	U	May	5	
1995	F	2007	V	June	6	
1996	Н	2008	W	July	7	
1997	J	2009	Х	August	8	
1998	K	2010	А	September	9	
1999	L	2011	В	October	0	
2000	М	2012	С	November	N	
2001	N	:	:	December	D	

repeats in a 20 year cycle

Factory identification mark

Factory identification Mark	Country of origin	
no mark	Lanan	
	Japan	
	Indonesia	
	China	

* This factory marking is for identification purpose only. Please Contact the local SHARP sales representative to see the actual status of the production.

Rank mark

Refer to the Model Line-up table

■ Absolute Maximum Ratings

	Absolute Maximum Ratings(Ta=25°C)						
	Parameter	Symbol	Rating	Unit			
t	Forward current	I _F	±10	mA			
Input	^{*1} Peak forward current	I _{FM}	±200	mA			
Ì	Power dissipation	Р	15	mW			
	Collector-emitter voltage	V _{CEO}	80	V			
Output	Emitter-collector voltage	V _{ECO}	6	V			
Out	Collector current	I _C	50	mA			
	Collector power dissipation	P _C	150	mW			
	Fotal power dissipation	P _{tot}	170	mW			
Operating temperature		T _{opr}	-30 to +100	°C			
Storage temperature		T _{stg}	-40 to +125	°C			
*2 Isolation voltage		V _{iso (rms)}	3.75	kV			
*3 🤆	Soldering temperature	T _{sol}	260	°C			

*1 Pulse width≤100μs, Duty ratio : 0.001 *2 40 to 60%RH, AC for 1 minute, f=60Hz

*3 For 10s

■ Electro-optical Characteristics

 $(T_a=25^{\circ}C)$

								(u /
	Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Inaut	Forward voltage		$V_{\rm F}$	I _F =±10mA	-	1.2	1.4	V
Input	Terminal capa	acitance	Ct	V=0, f=1kHz	-	30	250	pF
	Collector dark current		I _{CEO}	$V_{CE}=50V, I_{F}=0$	-	-	100	nA
Output	Collector-emitter breakdown voltage		BV _{CEO}	$I_{C}=0.1 \text{mA}, I_{F}=0$	80	_	_	V
	Emitter-collector breakdown voltage		BV _{ECO}	$I_{E}=10\mu A, I_{F}=0$	6	-	-	V
	Collector current		I _C	$I_F=\pm 0.5 \text{mA}, V_{CE}=5 \text{V}$	0.25	-	2.0	mA
	Collector-emitter saturation voltage		V _{CE (sat)}	$I_F = \pm 10 \text{mA}, I_C = 1 \text{mA}$	_	_	0.2	V
	Isolation resistance		R _{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10^{11}	-	Ω
Transfer	Floating capacitance		C_{f}	V=0, f=1MHz	_	0.6	1.0	pF
charac- teristics	Desmanae time	Rise time	t _r	V 2V I 2m A D 1000	_	4	18	μs
unsues	Response time	Fall time	$t_{\rm f}$	$V_{CE}=2V$, $I_C=2mA$, $R_L=100\Omega$	_	3	18	μs
	Common mode rejection voltage		CMR	$T_{a}=25^{\circ}C, R_{L}=470\Omega, V_{CM}=1.5kV(peak) \\ I_{F}=0, V_{CC}=9V, V_{np}=100mV$	10	_	_	kV/µs



■ Model Line-up

Package	Tap	oing	Rank mark	I _C [mA]
	3 000 pcs / reel	750 pcs / reel		$(I_F=\pm 0.5 \text{mA}, V_{CE}=5V, T_a=25^{\circ}\text{C})$
Model No.	PC364NJ0000F	PC364NTJ000F	with or without	0.25 to 2.0
	PC364N1J000F	PC364N1TJ00F	А	0.5 to 1.5

Please contact a local SHARP sales representative to inquire about production status.



Fig.1 Test Circuit for Common Mode Rejection Voltae



Fig.2 Forward Current vs. Ambient Temperature







Fig.3 Diode Power Dissipation vs. Ambient Temperature







Fig.6 Peak Forward Current vs. Duty Ratio

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Fig.7 Forward Current vs. Forward Voltage



Fig.9 Collector Current vs. Collector-emitter Voltage



Fig.11 Collector - emitter Saturation Voltage vs. Ambient Temperature





Fig.12 Collector Dark Current vs. Ambient Temperature











Fig.13 Response Time vs. Load Resistance (Active region)



Fig.15 Test Circuit for Response Time



Please refer to the conditions in Fig.13 and Fig. 14





Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.



Design Considerations

Design guide

While operating at I_{F} <0.5mA, CTR variation may increase. Please make design considering this fact.

In case that some sudden big noise caused by voltage variation is provided between primary and secondary terminals of photocoupler some current caused by it is floating capacitance may be generated and result in false operation since current may go through IRED or current may change.

If the photocoupler may be used under the circumstances where noise will be generated we recommend to use the bypass capacitors at the both ends of IRED.

This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

In general, the emission of the IRED used in photocouplers will degrade over time. In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

• Recommended Foot Print (reference)



(Unit : mm)

☆ For additional design assistance, please review our corresponding Optoelectronic Application Notes.



Manufacturing Guidelines

Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below. Soldering should not exceed the curve of temperature profile and time. Please don't solder more than twice.



Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 260°C and within 10s. Preheating is within the bounds of 100 to 150°C and 30 to 80s. Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C. Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



• Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3 minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC

This product shall not contain the following materials. And they are not used in the production process for this product. Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).
•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).



■ Package specification

• Tape and Reel package

1. 3 000pcs/reel

Package materials

Carrier tape : A-PET (with anti-static material)

Cover tape : PET (three layer system)

Reel : PS

Carrier tape structure and Dimensions



А	В	С	D	Е	F	G
$12.0^{\pm 0.3}$	$5.5^{\pm 0.1}$	$1.75^{\pm 0.1}$	$8.0^{\pm 0.1}$	$2.0^{\pm 0.1}$	$4.0^{\pm 0.1}$	φ1.5 ^{+0.1}
Н	Ι	J	K			
$7.4^{\pm 0.1}$	$0.3^{\pm 0.05}$	$3.1^{\pm 0.1}$	$4.0^{\pm 0.1}$			

Reel structure and Dimensions



Ŧ			
о ,			
	f		
	b	-	

Dimensio	ns List	(Unit : mm)		
а	b	С	d	
370	370 13.5 ^{±1.5}		13 ^{±0.5}	
e	f	g		
21 ^{±1.0}	$2.0^{\pm 0.5}$	$2.0^{\pm 0.5}$		

Direction of product insertion



[Packing : 3 000pcs/reel]



Package materials

2. 750 pcs / reel

Carrier tape : A-PET (with anti-static material)

Cover tape : PET (three layer system)

Reel : PS

Carrier tape structure and Dimensions



Reel structure and Dimensions



Dimensio	ns List	(Unit : mm)		
а	b	с	d	
180	180 13.5 ^{±1.5}		13 ^{±0.5}	
e	f	g		
21 ^{±1.0}	$2.0^{\pm 0.5}$	2.0 ^{±0.5}		

Direction of product insertion



[Packing : 750pcs/reel]

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- --- Personal computers
- --- Office automation equipment
- --- Telecommunication equipment [terminal]
- --- Test and measurement equipment
- --- Industrial control
- --- Audio visual equipment
- --- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:

- --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

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- --- Telecommunication equipment [trunk lines]
- --- Nuclear power control equipment
- --- Medical and other life support equipment (e.g., scuba).

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